

Zero-Drift, Single-Supply, Rail-to-Rail Input/Output Operational Amplifiers

■ General Description

The LN8551, LN8552 and LN8554 are single, dual and quad amplifiers featuring rail-to-rail input and output swings, which has ultralow offset, drift and bias current. All are guaranteed to operate from +2.7 V to +5 V single supply.

With an offset voltage of only 3 μ V and drift of 20 nV/ $^{\circ}$ C, the LN8551 is perfectly suited for applications where error sources cannot be tolerated. Temperature, position and pressure sensors, medical equipment and strain gage amplifiers benefit greatly from nearly zero drift over their operating temperature range. The rail-to-rail input and output swings provided by the LN855X family make both high-side and low- side sensing easy.

The LN855X series is specified for the extended industrial/automotive (-40 $^{\circ}$ C to +125 $^{\circ}$ C) temperature range. The LN8551 single is available in 5-lead SOT and 8-lead SOP/MSOP packages. The LN8552 dual amplifier is available in 8-lead SOP/MSOP packages. The LN8554 quad is available in narrow 14-lead SOP and 14-lead TSSOP packages.

■ Applications

- Temperature Measurements
- Pressure Sensors
- Precision Current Sensing
- Electronic Scales
- Strain Gage Amplifiers
- Medical Instrumentation
- Thermocouple Amplifiers
- Handheld Test Equipment

■ Features

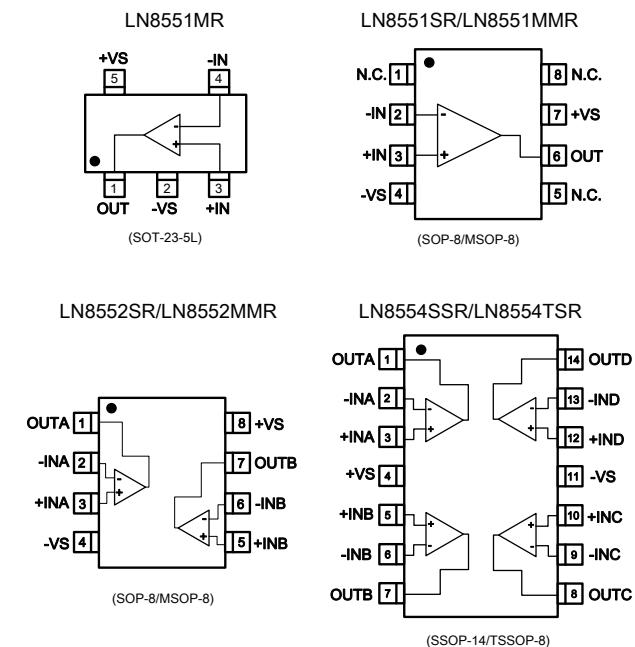
- Low Offset Voltage: 3 μ V (TYP)
- Rail-to-Rail Input and Output Swing
- 2.7V to 5.0V Single Supply Operation
- Voltage Gain: 145dB (TYP)
- PSRR: 115dB (TYP)
- CMRR: 110dB (TYP)
- Low Input Bias Currents: 130pA
- Low Supply Current: 450 μ A/Channel
- Overload Recovery Time: 0.1ms
- No External Capacitors Required
- -40 $^{\circ}$ C to +125 $^{\circ}$ C Operating Temperature Range
- Small Packaging:

LN8551 Available in Green SOT-23-5L, SOP8 and MSOP8

LN8552 Available in Green SOP8 and MSOP8

LN8554 Available in Green SOP14

■ Package



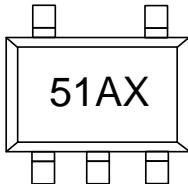
■ Ordering Information

LN855 ①②③

Designator	Symbol	Description
①		Product No.
	1	LN8551
	2	LN8552
	4	LN8554
②	—	Package
	M	SOT-23-5
	S	SOP-8
	MM	MSOP-8
	SS	SSOP-14
	TS	TSSOP-14
③	—	Device Orientation
	R	Embossed Tape: Standard Feed
	L	Embossed Tape: Reverse Feed

■ Marking

LN8551MR



51---LN8551MR
A----die code
X---process code

LN855①②③



LN855①---LN8551 or LN8552 or LN8554
XXXX---process code
YYYYYY---lot code

■ Absolute Maximum Ratings

- ◊ Supply Voltage.....6V
- ◊ Input Voltage.....-VS+0.3V—+VS+0.3V
- ◊ Differential Input Voltage.....-5.0V to +5.0V
- ◊ Package Thermal Resistance @ TA = 25°C
SOT-23-5L.....190°C/W
MSOP-8.....216°C/W
SOP-8.....125°C/W
SSOP-14.....120°C/W
TSSOP-14.....180°C/W
- ◊ Storage temperature range.....-65°C to 150°C
- ◊ Operating junction temperature.....-40°C to 125°C
- ◊ ESD Human Model.....4000V
- ◊ Lead Temperature Range (Soldering 10 sec).....260°C

■ Electrical Characteristics

(VS = +5V, VCM = +2.5V, VO = +2.5V, TA = +25°C, unless otherwise noted.)

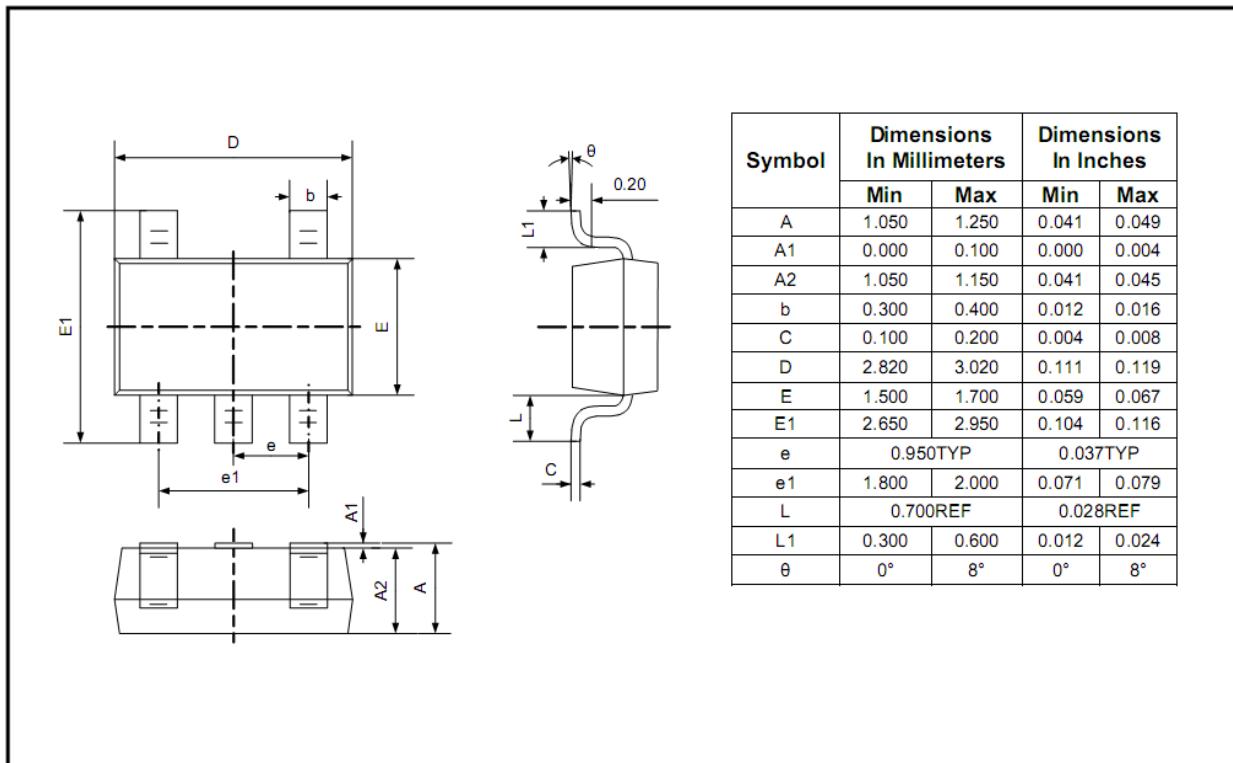
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V _{os}	Input Offset Voltage		—	3	10	µV
I _B	Input Bias Current			100		pA
I _{os}	Input Offset Current			10		pA
CMRR	Common-Mode Rejection Ratio	V _{CM} = 0V to 5V		110		dB
A _{vo}	Large Signal Voltage Gain	R _L = 10kΩ V _O =0.3V~4.7V		145		dB
ΔV _{os} /ΔT	Input Offset Voltage Drift			20		nV/°C
OUTPUT CHARACTERISTICS						
V _{OH}	Output Voltage High	RL = 100kΩ to -VS		4.998		V
		RL = 10kΩ to -VS		4.994		V
V _{OL}	Output Voltage Low	RL = 100kΩ to +VS		2		mV
		RL = 10kΩ to +VS		5		mV
I _{sc}	Short Circuit Limit	RL = 10Ω to -VS		43		mA
I _o	Output Current			30		mA
POWER SUPPLY						
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V		115		dB
I _Q	Quiescent Current	VO = 0V, RL = 0Ω		450		µA
DYNAMIC PERFORMANCE						
GBP	Gain-Bandwidth Product	G = +100		1.44		MHz
SR	Slew Rate	RL = 10kΩ		0.84		V/µs
T _{OR}	Overload Recovery Time			0.10		ms
NOISE PERFORMANCE						
e _n p-p	Voltage Noise	0Hz to 10Hz		0.81		µVp-p
e _n	Voltage Noise Density	f = 1kHz		49		nV/√Hz

(VS = +2.7V, VCM = +1.35V, VO = +1.35V, TA = +25°C, unless otherwise noted.)

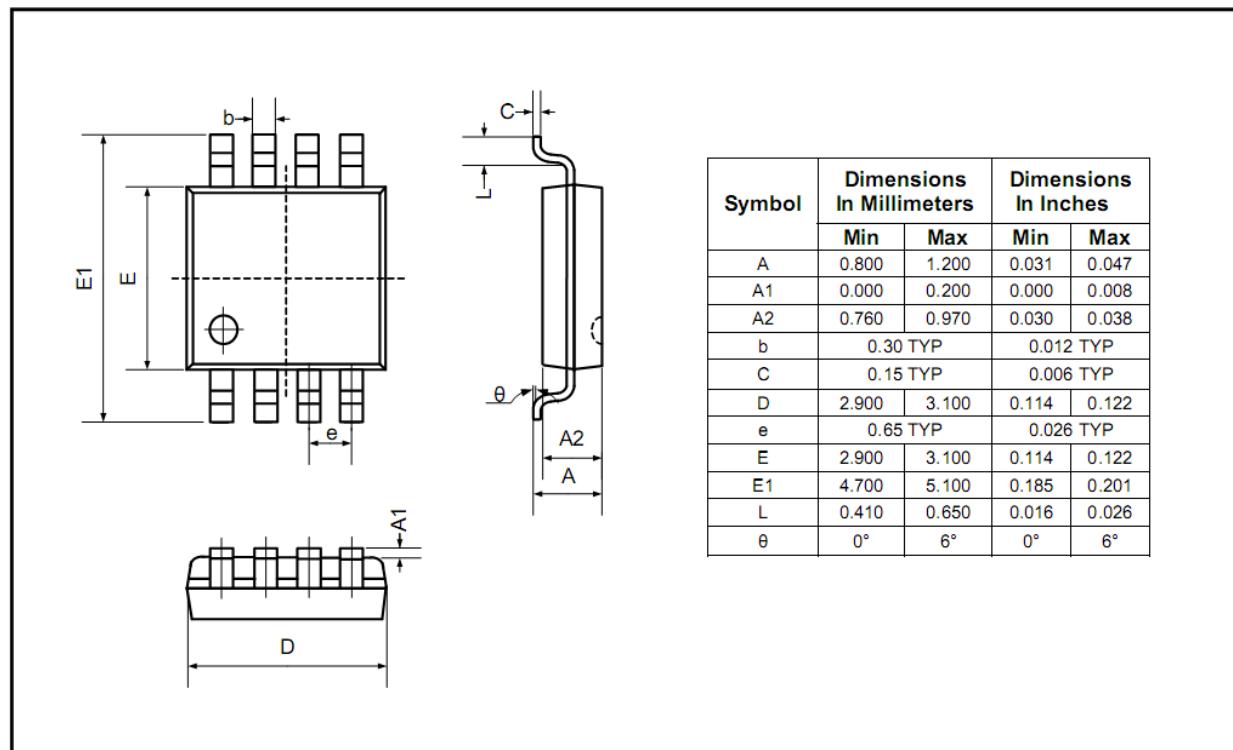
Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
INPUT CHARACTERISTICS						
V _{os}	Input Offset Voltage		—	3	10	µV
I _B	Input Bias Current		75			pA
I _{os}	Input Offset Current		5			pA
CMRR	Common-Mode Rejection Ratio	V _{CM} = 0V to 2.7V	110			dB
A _{vo}	Large Signal Voltage Gain	R _L = 10kΩ V _O =0.3V~2.4V	140			dB
ΔV _{os} /ΔT	Input Offset Voltage Drift		20			nV/°C
OUTPUT CHARACTERISTICS						
V _{OH}	Output Voltage High	RL = 100kΩ to -VS		2.699		V
		RL = 10kΩ to -VS		2.697		V
V _{OL}	Output Voltage Low	RL = 100kΩ to +VS		1		mV
		RL = 10kΩ to +VS		2		mV
I _{sc}	Short Circuit Limit	RL = 10Ω to -VS	26			mA
I _o	Output Current		10			mA
POWER SUPPLY						
PSRR	Power Supply Rejection Ratio	VS = 2.7V to 5.5V	115			dB
I _Q	Quiescent Current	VO = 0V, RL = 0Ω	450			µA
DYNAMIC PERFORMANCE						
GBP	Gain-Bandwidth Product	G = +100	1.43			MHz
SR	Slew Rate	RL = 10kΩ	0.84			V/µs
T _{OR}	Overload Recovery Time		0.04			ms
NOISE PERFORMANCE						
e _n p-p	Voltage Noise	0Hz to 10Hz	0.90			µVp-p
e _n	Voltage Noise Density	f = 1kHz	53			nV/√Hz

■ Package Information

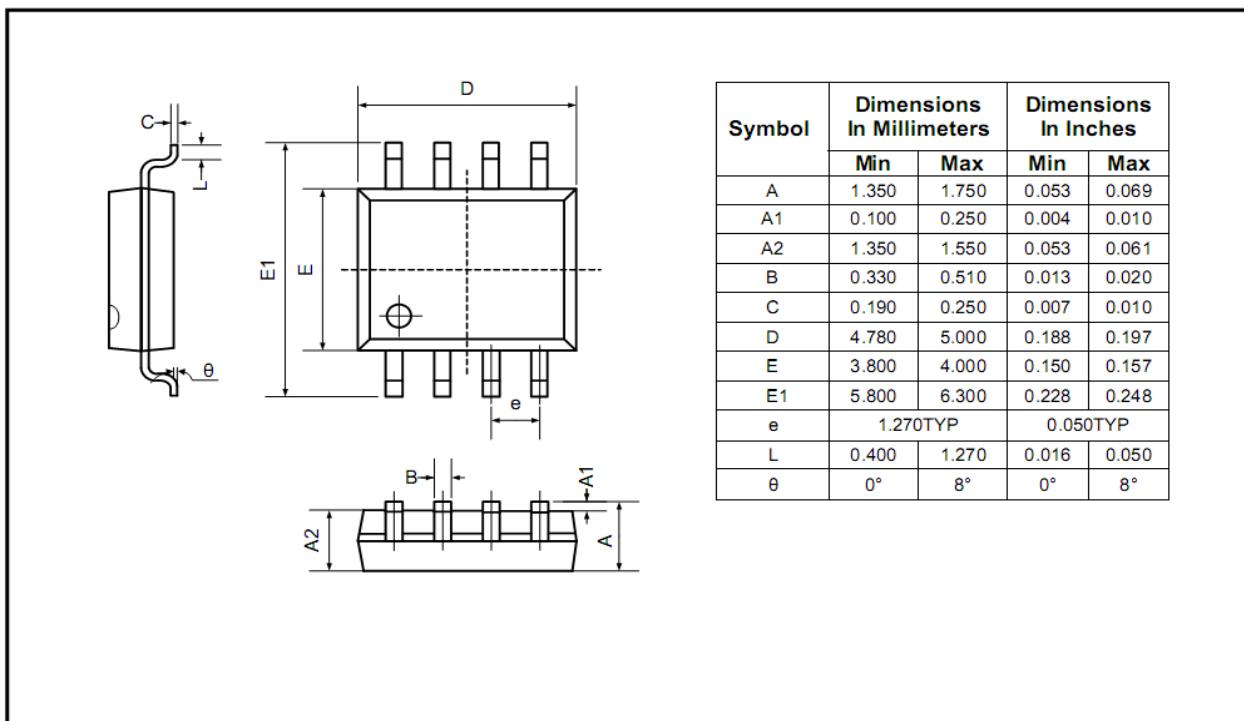
SOT-23-5L



MSOP8



SOP8



SOP14

